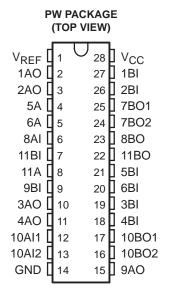
SCES619 - DECEMBER 2004

- Operates as GTL-/GTL/GTL+ to LVTTL or LVTTL to GTL-/GTL/GTL+ Translator
- Series Termination on TTL Outputs of 30 Ω
- Latch-Up Testing to JEDEC Standard JESD 78 Exceeds 500 mA
- **ESD Performance Tested Per JESD 22**
 - 2000-V Human-Body Model (A114-B, Class II)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

description

The SN74GTL2006 is a 13-bit translator to interface between the 3.3-V LVTTL chipset I/O and the Xeon™ processor GTL-/GTL/GTL+ I/O. The device is designed for platform health management in dual-processor applications.



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	VREF	GTL reference voltage
2–6, 8, 10–13, 15	nAn	Data inputs/outputs (LVTTL)
7, 9, 16, 17–27	nBn	Data inputs/outputs (GTL-/GTL/GTL+)
14	GND	Ground (0 V)
28	VCC	Positive supply voltage

ORDERING INFORMATION

TA	PACKAG	ΕŤ	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	TOCOD DW	Tube	SN74GTL2006PW	GK2006
	TSSOP – PW	Tape and reel	SN74GTL2006PWR	GK2006

[†]Package drawings, standard packing quantities, thermal data, symbolization, and PCB design, guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners



Function Tables

INPUTS 1BI/2BI/3BI/4BI/9BI	OUTPUTS 1AO/2AO/3AO/4AO/9AO
L	L
Н	Н

INPUT 8AI	OUTPUT 8BO
L	L
Н	Н

INPUTS	OUTPUTS	
10AI1/10AI2	9BI	10BO1/10BO2
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

INPUTS 5BI/6BI	INPUTS/OUTPUTS 5A/6A (OPEN DRAIN)	OUTPUTS 7BO1/7BO2
L	L	H [†]
Н	L‡	L
Н	Н	Н

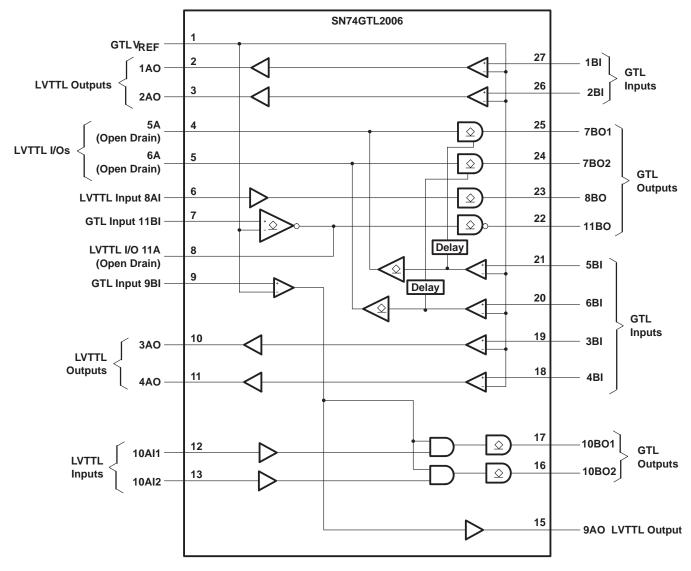
[†] The enable on 7BO1/7BO2 includes a delay that prevents a transient condition (when 5BI/6BI goes from low to high, and the low to high on 5A/6A lags up to 100 ns) from causing a low glitch on the 7BO1/7BO2 outputs.

[‡] Open-drain input/output terminal is driven to a logic-low state by an external driver.

INPUT 11BI	INPUT/OUTPUT 11A (OPEN DRAIN)	OUTPUT 11BO
L	Н	L
L	L‡	Н
Н	L	Н

[‡] Open-drain input/output terminal is driven to a logic-low state by an external driver.

logic symbol



NOTE A: The enable on 7BO1/7BO2 includes a delay that prevents a transient conditon (where 5BI/6BI go from low to high, and the low to high on 5A/6A lags up to 100 ns) from causing a low glitch on the 7BO1/7BO2 outputs.

SCES619 - DECEMBER 2004

absolute maximum ratings over operating free-air temperature (unless otherwise noted)^{†‡}

Supply voltage range, V _{CC}	
Input voltage range, V _I (see Note 2): A port (LVTTL)	–0.5 to 4.6 V
B port (GTL)	–0.5 to 4.6 V
Output voltage range, VO (output in OFF or HIGH state)(see Note 2): A port	
B port	
Input diode current, $I_{ K }(V_{ C } < 0)$	–50 mA
Output diode current, I _{OK} (V _O < 0)	–50 mA
Current into any output in the LOW state: A port	32 mA
B port	30 mA
Current into any output in the HIGH state, A port	–32 mA
Storage temperature range, T _{stq}	–60 to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The performance capability of a high-performance integrated circuit, in conjunction with its thermal environment, can create junction temperatures that are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

2. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

recommended operating conditions

			MIN	NOM	MAX	UNIT	
VCC	Supply voltage		3	3.3	3.6	V	
		GTL-	0.85	0.9	0.95		
VTT	Termination voltage	GTL	1.14	1.2	1.26	V	
		GTL+	1.35	1.5	1.65]	
		Overall	0.5	2/3 V _{TT}	1.8		
.,	B. ()	GTL-	0.5	0.6	0.63] ,	
V _{REF}	Reference voltage	GTL	0.76	0.8	0.84	V	
		GTL+	0.87	1	1.1	1	
		A port	0	3.3	3.6	,,	
VI	Input voltage	B port	0	VTT	3.6	V	
		A port	2				
V_{IH}	High-level input voltage	B port	V _{REF} + 50 m	V		V	
		A port			0.8		
V_{IL}	Low-level input voltage	B port			V _{REF} - 50 mV	V	
ІОН	High-level output current	A port			-16	mA	
		A port			16		
lOL	Low-level output current	B port			15	mA	
TA	Operating free-air temperature range	•	-40		85	°C	



[‡] Voltages are referenced to GND (ground = 0 V).

SCES619 - DECEMBER 2004

electrical characteristics over recommended operating conditions

	DADAMETED		TEST CONDITIONS			-40°C TO 85°C			
	PARAMETER	IESI	MIN	TYP [†]	MAX	UNIT			
\ , +	Amad	$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OH} = -100 μA	V _{CC} - 0.2			V		
V _{OH} ‡	A port	V _{CC} = 3 V,	I _{OH} = -16 mA	2.1			V		
v +	A port	$V_{CC} = 3 V$,	I _{OL} = 16 mA			0.8	.,		
V _{OL} ‡	B port	V _{CC} = 3 V,	I _{OL} = 15 mA			0.4	V		
	A	.,	VI = VCC			±1			
I _I	A port	V _{CC} = 3.6 V	V _I = 0 V			±1	μΑ		
	B port	V _{CC} = 3.6 V,	$V_I = V_{TT}$ or GND			±1			
Icc	A or B port	V _{CC} = 3.6 V,	$V_I = V_{CC}$ or GND, $I_O = 0$			12	mA		
Δlcc§	A port or control inputs	V _{CC} = 3.6 V,	VI = VCC - 0.6 V			500	μΑ		
Cur	A port	$V_{O} = 3 \text{ V or } 0,$	V _O = 3 V or 0		5		, F		
CIO	B port	$V_O = V_{TT}$ or 0,	$V_O = V_{TT}$ or 0		4		pF		

[†] All typical values are measured at V_{CC} = 3.3 V and T_A = 25°C.

switching characteristics over recommended operating free-air temperature range

PARAMETER				GTL-			GTL		GTL+			
		WAVEFORM	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V},$ $V_{REF} = 0.6 \text{ V}$			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V},$ $V_{REF} = 0.8 \text{ V}$			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V},$ $V_{REF} = 1 \text{ V}$			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
^t PLH	An to Bn	1	2	4	8	2	4	8	2	4	8	20
^t PHL	An to bn	ı	2	5.5	10	2	5.5	10	2	5.5	10	ns
^t PLH	Bn to An	2	2	5.5	10	2	5.5	10	2	5.5	10	20
^t PHL	BII to Ali	2	2	5.5	10	2	5.5	10	2	5.5	10	ns
^t PLH	9BI to 10BOn	3	2	6	11	2	6	11	2	6	11	20
^t PHL	961 (0 1060)1	3	2	6	11	2	6	11	2	6	11	ns
^t PLH	11BI to 11BO	3	2	8	13	2	8	13	2	8	13	20
$t_{PHL}\P$	116110 1160	3	2	14	21	2	14	21	2	14	21	ns
^t PLH	Bn to Bn	3	4	7	11	4	7	11	4	7	11	20
tPHL	DII (U DII	3	120	205	350	120	205	350	120	205	350	ns
tPLZ	Bn to An (I/O)	4	2	5	10	2	5	10	2	5	10	ns
^t PZL	Bit to Air (1/0)	7	2	5	10	2	5	10	2	5	10	113

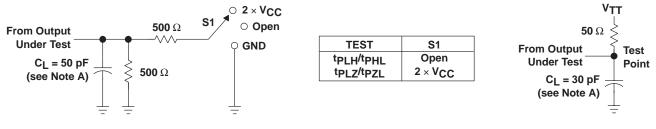
[†] All typical values are measured at $V_{CC} = 3.3 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.



[†] The input and output voltage ratings may be exceeded if the input and output current ratings are observed. § This is the increase in supply current for each input that is at the specified LVTTL voltage, rather than V_{CC} or GND.

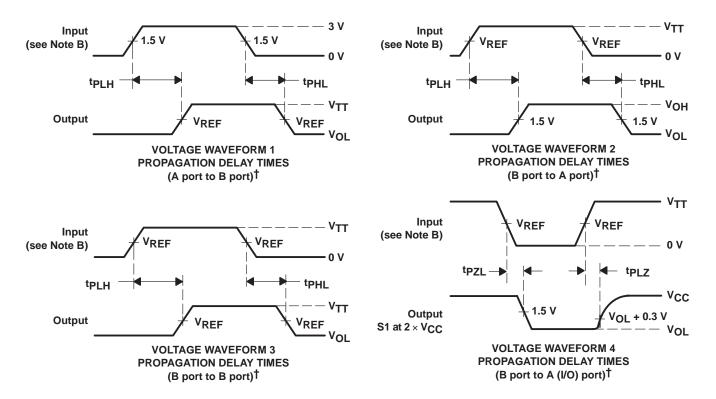
[¶] Includes ~7.6-ns RC rise time of test-load pullup on 11-A, 1.5-kΩ pullup, and 21-pF load on 11 A has approximately 23-ns RC rise time.

PARAMETER MEASUREMENT INFORMATION V_{TT} = 1.2 V, V_{REF} = 0.8 V FOR GTL AND V_{TT} = 1.5 V, V_{REF} = 1 V FOR GTL+



LOAD CIRCUIT FOR A OUTPUTS

LOAD CIRCUIT FOR B OUTPUTS



† All control inputs are LVTTL levels.

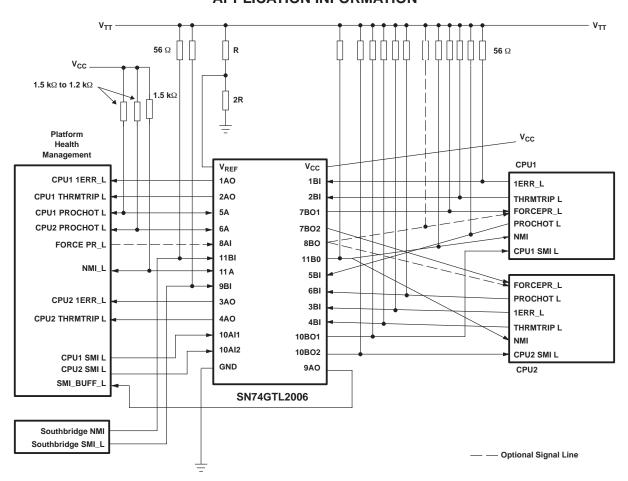
NOTES: A. C_L includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- C. The outputs are measured one at a time, with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms



APPLICATION INFORMATION



frequently asked questions

Question 1: On SN74GTL2006 LVTTL inputs, specifically 10Al1 and 10Al2, when the device is powered down, these inputs may be pulled up to 3.3 V, and we want to ensure that there is no leakage path to the power rail under this condition. Are the LVTTL inputs high impedance when the device is powered down, and will there be any leakage?

Answer 1: When the device is powered down, the LVTTL inputs are in a high-impedance state and do not leak to V_{DD} if they are pulled high while the device is powered down.

Question 2: Do all the LVTTL inputs have the same powered-down characteristic?

Answer 2: Yes

Question 3: What is the condition of the other GTL I/O and LVTTL output pins when the device is powered down?

Answer 3: The open-drain outputs, both GTL and LVTTL, do not leak to the power supply if they are pulled high while the device is powered down. The GTL inputs also do not leak to the power supply under the same conditions. The LVTTL totem-pole outputs, however, are not open-drain type outputs, and there will be current flow on these pins if they are pulled high when V_{DD} is at ground.





PACKAGE OPTION ADDENDUM

10-Jun-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74GTL2006PWR	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GK2006	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





10-Jun-2014

PACKAGE MATERIALS INFORMATION

www.ti.com 15-Jul-2018

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74GTL2006PWR	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 15-Jul-2018

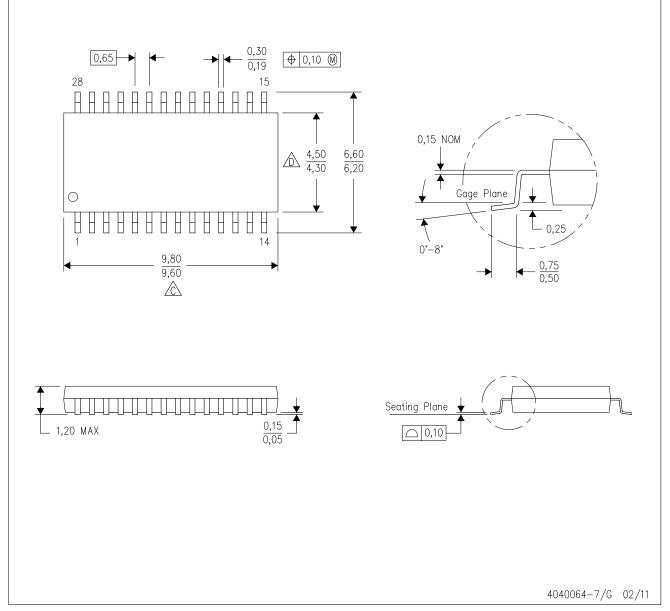


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74GTL2006PWR	TSSOP	PW	28	2000	367.0	367.0	38.0	

PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2019, Texas Instruments Incorporated